




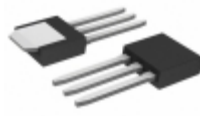




	<p>Hersteller-Teilenummer: NTD60N03T4</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 28V 60A DPAK</p>
	<p>Datenblätter:  NTD60N03T4.pdf</p>
	<p>RoHs Status: Enthält Blei / RoHS nicht konform</p>
	<p>Lagerzustand: New original, 10040 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NTD60N03T4
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 28V 60A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10040 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	75W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	28V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2150pF @ 24V
Verpackung	Tape & Reel (TR)



















































NTD60N03T4 ist neu im Original, Suche NTD60N03T4 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD60N03T4 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD60N03T4: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD60N02RT ON NTD60N02RT ON</p>	 <p>NTD6414ANLT4G AMI Semiconductor / ON Semiconductor NTD6414ANLT4G ON</p>	 <p>NTD60N02RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 8.5A DPAK</p>	 <p>NTD6414AN-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 32A IPAK</p>
 <p>NTD60N03-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 28V 60A IPAK</p>	 <p>NTD60N03T4G ON NTD60N03T4G ON</p>	 <p>NTD60N06HD MOT NTD60N06HD MOT</p>	 <p>NTD60N03RT4G O NTD60N03RT4G O</p>

heiße Teile

Mehr

- | | | | | |
|---|---|--|--|---|
|  NTD5862NT4G |  NTD5865N-1G |  NTD5865NL |  NTD5865NL-1G |  NTD5865NLT4G |
|  NTD5865NT4G |  NTD5867NL |  NTD5867NL-1G |  NTD5867NLG |  NTD5867NLT4G |
|  NTD5867NT4G |  NTD60N02KG |  NTD60N02R |  NTD60N02R-001 |  NTD60N02R-032 |
|  NTD60N02R-035 |  NTD60N02R-1G |  NTD60N02R-1R |  NTD60N02R-35G |  NTD60N02RG |
|  NTD60N02RG-1G |  NTD60N02RT |  NTD60N02RT4 |  NTD60N02RT4G |  NTD60N03RT4G |
|  NTD60N03T4G |  NTD6414AN |  NTD6414AN-1G |  NTD6414ANT4G |  NTD6414AUG |
|  NTD6415AN |  NTD6415AN-1G |  NTD6415ANL |  NTD6415ANLT4G |  NTD6415ANT4G |
|  NTD6416AN |  NTD6416AN-1G |  NTD6416ANG |  NTD6416ANL |  NTD6416ANL-1G |
|  NTD6416ANLT4G |  NTD6416ANT4G |  NTD65N03G |  NTD65N03R-001 |  NTD65N03R-035 |
|  NTD65N03R-1G |  NTD65N03R-35G |  NTD65N03RG |  NTD65N03RT4G |  NTD6600G |

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